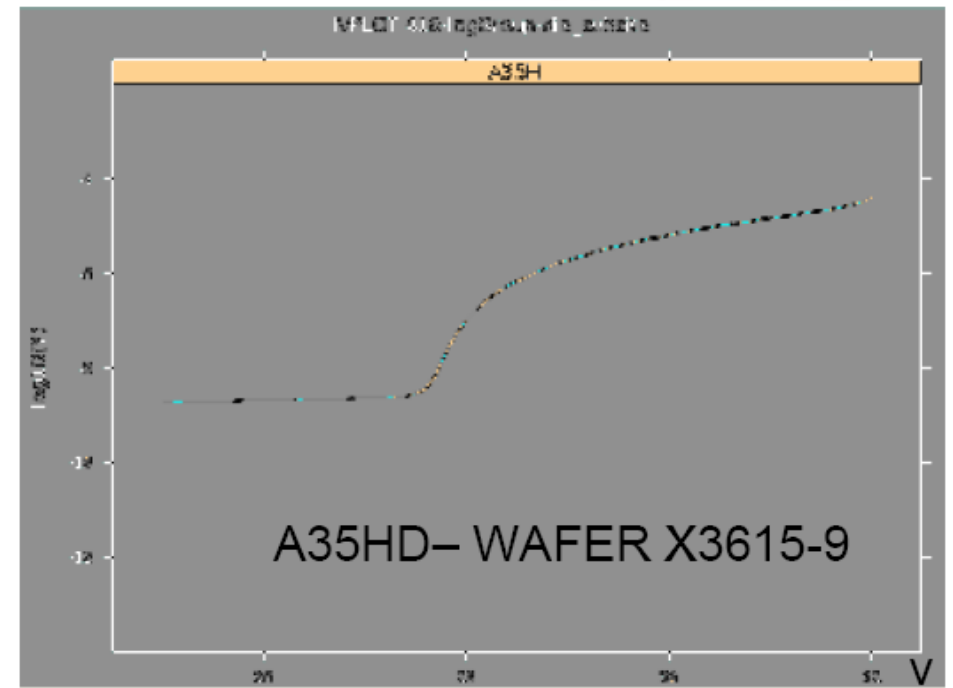
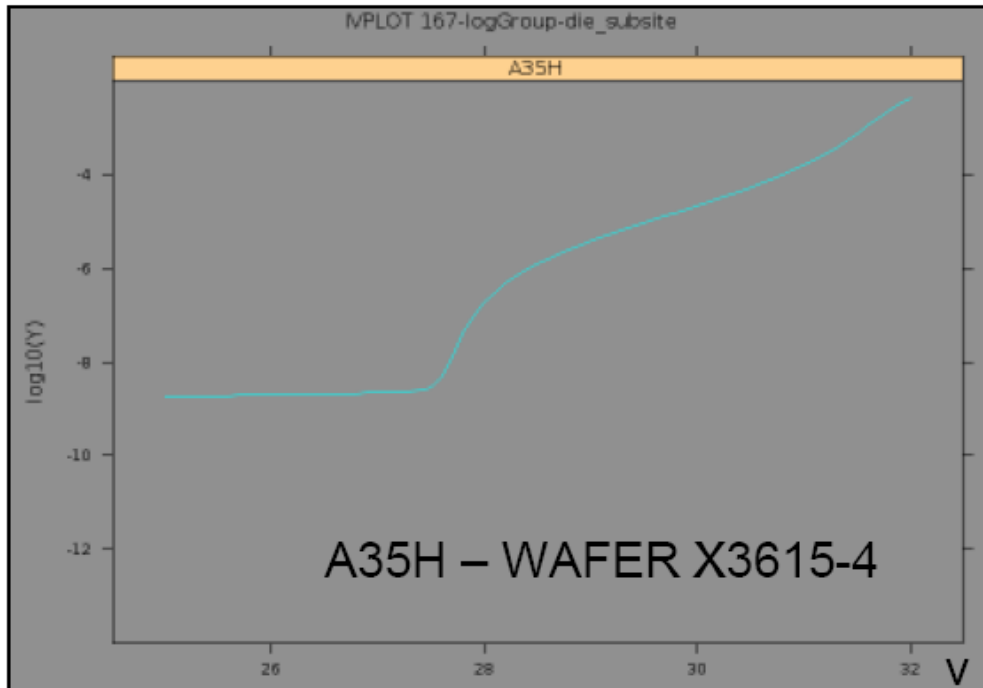


# A35H SPM IV CHARACTERISTICS



PARAMETER	DEFINITION	LOWER SCREEN LIMIT	UPPER SCREEN LIMIT
VBR	BREAKDOWN VOLTAGE – REVERSE BIAS VOLTAGE AT WHICH 10nA FLOWS	27.5 V	27.9 V
IR30	DARK CURRENT, MEASURED AT 30V REVERSE BIAS	5.0E-7 A	5.0E-5 A
IR32	DARK CURRENT, MEASURED AT 32V REVERSE BIAS	5.0E-6 A	1.0E-2 A*

\*Tighter screen limit of 6.0E-5A is used for A35HD device on wafer X3615-9